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FUJITSU SEMICONDUCTOR DATA SHEET

查询MB15F02PV供应商

ASSP Dual Serial Input PLL Frequency Synthesizer

MB15F02

DESCRIPTION

The Fujitsu MB15F02 is a serial input Phase Locked Loop (PLL) frequency synthesizer with a 2.0 GHz and a 500 MHz prescalers. A 64/65 or a 128/129 for the 1.2 GHz prescaler, and a 16/17 or a 32/33 for 500 MHz prescaler can be selected that enables pulse swallow operation.

The latest BiCMOS process technology is used, resultantly a supply current is limited as low as 6.0 mA typ. at a supply voltage of 3.0 V.

Furthermore, a super charger circuit is included to provide a fast tuning as well as low noise performance. As a result of this, MB15F02 is ideally suitable for digital mobile communications, such as GSM (Global System for Mobile Communications).

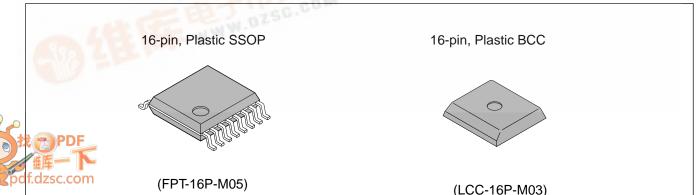
FEATURES

• High frequency operation RF synthesizer : 1.2 GHz max.

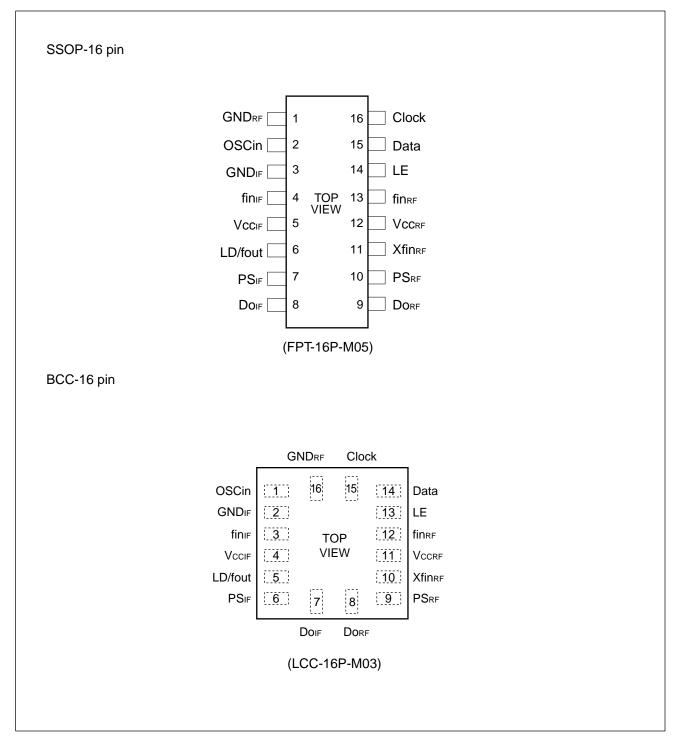
IF synthesizer : 500 MHz max.

- Low power supply voltage: Vcc = 2.7 to 3.6V
- Very Low power supply current : Icc = 6.0 mA typ. (Vcc = 3 V)
- Power saving function : IPS1 = IPS2 = 0.1 μA typ.
- Serial input 14-bit programmable reference divider: R = 5 to 16,383
- Serial input 18-bit programmable divider consisting of:
 - Binary 7-bit swallow counter: 0 to 127
- Binary 11-bit programmable counter: 5 to 2,047
- On-chip high performance charge pump circuit and phase comparator, achieving high-speed lock-up and low phase noise
- Wide operating temperature: Ta = -40 to $85^{\circ}C$
- Plastic 16-pin SSOP package (FPT-16P-M05) and 16-pin BCC package (LCC-16P-M03)

PACKAGES



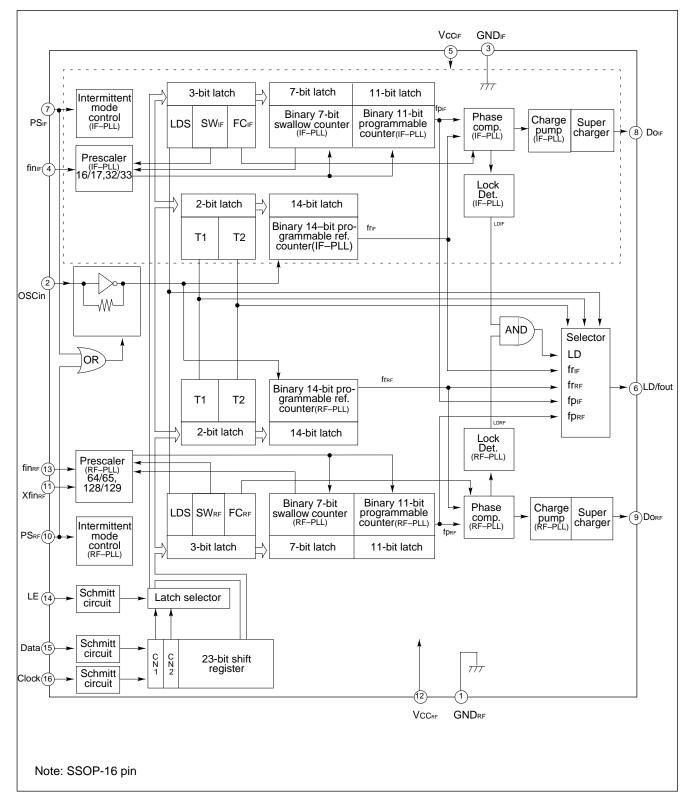
■ PIN ASSIGNMENTS



■ PIN DESCRIPTIONS

Pin No.		Pin	1/0	Descriptions				
SSOP	BCC	name	I/O	Descriptions				
1	16	GNDrf	-	Ground for RF–PLL section.				
2	1	OSCin	I	The programmable reference divider input. TCXO should be connected with a coupling capacitor.				
3	2	GNDIF	-	Ground for the IF-PLL section.				
4	3	finı⊧	I	Prescaler input pin for the IF-PLL. The connection with VCO should be AC coupling.				
5	4	Vccif	-	Power supply voltage input pin for the IF-PLL section.				
6	5	LD/fout	0	Lock detect signal output (LD) / phase comparator monitoring output (fout) The output signal is selected by a LDS bit in a serial data. LDS bit = "H" ; outputs fout signal LDS bit = "L" ; outputs LD signal				
7	6	PSIF	I	Power saving mode control for the IF-PLL section. This pin must be set at "L" Power-ON. (Open is prohibited.) $PS_{IF} = "H"$; Normal mode $PS_{IF} = "L"$; Power saving mode				
8	7	Doif	0	Charge pump output for the IF-PLL section. Phase characteristics of the phase detector can be reversed by FC-bit.				
9	8	Dorf	0	Charge pump output for the RF-PLL section. Phase characteristics of the phase detector can be reversed by FC-bit.				
10	9	PS _{RF}	I	Power saving mode control for the RF-PLL section. This pin must be set at "L" Power-ON. (Open is prohibited.) $PS_{RF} =$ "H"; Normal mode $PS_{RF} =$ "L"; Power saving mode				
11	10	Xfinrf	I	Prescaler complimentary input for the RF-PLL section. This pin should be grounded via a capacitor.				
12	11	VCCRF	-	Power supply voltage input pin for the RF-PLL section, the shift register and the oscillator input buffer.				
13	12	finrf	I	Prescaler input pin for the RF-PLL. The connection with VCO should be AC coupling.				
14	13	LE	I	Load enable signal input (with the schmitt trigger circuit.) When LE is "H", data in the shift register is transferred to the corresponding latch according to the control bit in a serial data.				
15	14	Data	I	Serial data input (with the schmitt trigger circuit.) A data is transferred to the corresponding latch (IF-ref counter, IF-Prog. counter, RF-ref. counter, RF-prog. counter) according to the control bit in a serial data.				
16	15	Clock	I	Clock input for the 23-bit shift register (with the schmitt trigger circuit. One bit data is shifted into the shift register on a riging edge of the clock.				

BLOCK DIAGRAM



Parameter	Symbol	Rating	Unit	Remark
Power supply voltage	Vcc	-0.5 to +4.0	V	
Input voltage	Vı	-0.5 to Vcc +0.5	V	
Output voltage	Vo	-0.5 to Vcc +0.5	V	
Storage temperature	Тѕтс	-55 to +125	°C	

■ ABSOLUTE MAXIMUM RATINGS

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol		Value	Unit	Note	
Faialletei	Symbol	Min.	Тур.	Max.	Unit	Note
Power supply voltage	Vcc	2.7	3.0	3.6	V	
Input voltage	Vi	GND	_	Vcc	V	
Operating temperature	Та	-40	_	+85	°C	

WARNING: Recommended operating conditions are normal operating ranges for the semiconductor device. All the device's electrical characteristics are warranted when operated within these ranges.

Always yse semiconductor devices within the recommended operating conditions. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with repect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representative beforehand.

ELECTRICAL	CHARACTERISTICS
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Damage		0	O and little a		Value	V, Ta = -40 to		
Paramete	er	Symbol	Condition	Min.	Тур.	Max.	Unit	
Power supply cu	rront	Iccif ^{*1}	finı⊧ = 500 MHz, fosc = 12 MHz	-	2.5	-	mA	
rower supply cu	ineni	ICCRF ^{*2}	fin _{RF} = 1200 MHz, fosc = 12 MHz	-	3.5	-		
Power saving current		Ipsı⊧	VcciF current at PSiF ="L"	_	0.1 ^{*3}	10	μA	
) Deprating		Ipsrf	Vccrf current at PSIF/RF ="L"	_	0.1 ^{*3}	10	μΑ	
O	fin⊧	finı⊧*4	IF–PLL	50	-	500		
Operating frequency	finrf	finrf ^{*4}	RF–PLL	100	-	1200	MHz	
noquonoy	OSCin	fosc		3	-	40		
	fin⊧	Vfinı⊧	IF–PLL, 50 Ω load system (Refer to the TEST CIRCUIT)	-10	-	+2	dBm	
Input sensitivity	finrf	Vfinrf	RF–PLL, 50 Ω load system (Refer to the TEST CIRCUIT)	-10	-	+2	dBm	
	OSCin	Vosc		0.5	_	Vcc	Vp-p	
	Data,	Vін	Schmitt trigger input	Vcc×0.7+0.4	_			
Input voltage	Clock, LE	VIL	Schmitt trigger input	_	_	Vcc×0.3-0.4	V	
	PSIF,	Vih		Vcc×0.7	-		v	
	PSrf	VIL		_	-	Vcc×0.3	V	
	Data,	I ін ^{*5}		-1.0		+1.0		
Input current	Clock, LE, PSif, PSrf	lı∟*5		-1.0	-	+1.0	μA	
	OSCin	Ін		0		+100		
	USCIII	Iı∟* ⁵		-100	-	0	μA	
	LD/fout	Vон	Vcc = 3.0 V, Іон = –1 mA	Vcc-0.4	_		V	
	LD/IOUL	Vol	Vcc = 3.0 V, IoL = 1 mA	-	-	0.4	V	
Output voltage	Doif,	Vdoh	Vcc = 3.0 V, Іон = –1 mA	Vcc-0.4	-		V	
	DORF	Vdol	Vcc = 3.0 V, IoL = 1 mA	-	-	0.4	V	
High impedance cutoff current	Doif, Dorf	IOFF	Vcc = 3.0 V VoFF = GND to Vcc	_	_	1.1	μA	
		І он ^{*5}	Vcc = 3.0 V	_	_	-1.0	m	
	LD/fout	Iol	Vcc = 3.0 V	1.0	_	_	mA	
Output current	Doif,	Ірон*5	Vcc = 3.0 V, V _{DOH} = 2.0 V, Ta = 25°C	-11	_	-6		
	DORF	IDOL	Vcc = 3.0 V, V _{DOL} = 1.0 V, Ta = 25°C	a = 25°C 8 –		15	- mA	

 $(V_{CC} = 2.7 \text{ to } 3.6 \text{ V}. \text{ Ta} = -40 \text{ to } +85^{\circ}\text{C})$

*1: Conditions ; Vcc = 3.0 V, Ta = 25°C, in locking state.

*2: Conditions; $V_{CRF} = 3.0 \text{ V}$, $T_a = 25^{\circ}\text{C}$, in locking state.

*3: Conditions ; Vcc = 3.0 V, fosc = 12.8 MHz (-2 dB), Ta = 25°C

*4: AC coupling. The minimum frequency is specified with a connecting coupling capacitor of 1000 pF.

*5: The symbol "--" means direction of current flow.

■ FUNCTIONAL DESCRIPTIONS

The divide ratio can be calculated using the following equation:

 $f_{VCO} = \{(M \times N) + A\} \times f_{OSC} \div R \quad (A < N)$

fvco: Output frequency of external voltage controlled ocillator (VCO)

M: Preset divide ratio of dual modulus prescaler (16 or 32 for IF-PLL, 64 or 128 for RF-PLL)

N: Preset divide ratio of binary 11-bit programmable counter (5 to 2,047)

A: Preset divide ratio of binary 7-bit swallow counter ($0 \le A \le 127$)

fosc: Reference oscillation frequency

R: Preset divide ratio of binary 14-bit programmable reference counter (5 to 16,383)

Serial Data Input

Serial data is entered using three pins, Data pin, Clock pin, and LE pin. Programmable dividers of IF/RF–PLL sections, programmable reference dividers of IF/RF PLL sections are controlled individually.

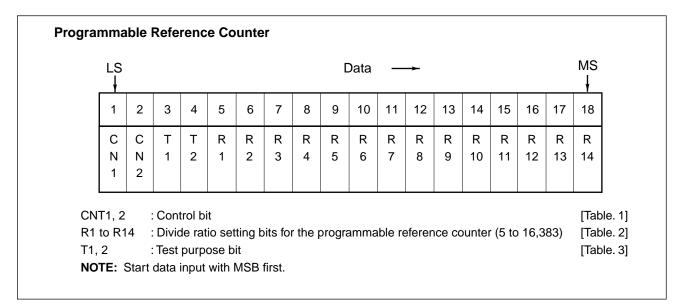
Serial data of binary data is entered through Data pin.

On rising edge of clock, one bit of serial data is transferred into the shift register. When load enable signal is high, the data stored in the shift register is transferred to one of latch of them depending upon the control bit data setting.

Cor	ntrol bit	Destination of serial data
CN1	CN2	Destination of serial data
L	L	The programmable reference counter for the IF-PLL.
Н	L	The programmable reference counter for the RF-PLL.
L	Н	The programmable counter and the swallow counter for the IF-PLL
Н	Н	The programmable counter and the swallow counter for the RF-PLL

Table1. Control Bit

Shift Register Configuration



Programmable Counter

LS ↓								C	Data													MS
1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21	22	23
C N 1	C N 2	L D S	S W	F C	A 1	A 2	A 3	A 4	A 5	A 6	A 7	N 1	N 2	N 3	N 4	N 5	N 6	N 7	N 8	N 9	N 10	N 11
	CNT1, 2 : Control bit [Table. 1] N1 to N14 : Divide ratio setting bits for the programmable counter (5 to 2,047) [Table. 4] A1 to A7 : Divide ratio setting bits for the swallow counter (0 to 127) [Table. 5] SW : Divide ratio setting bit for the prescaler (16/17 or 32/33 for the IF-PLL, 64/65 or 128/129 for the RF-PLL) [Table. 6]																					
		FC LDS NOT	E: Si	: L	Phase _D/fou ata in	ıt sigr	nal se	lect b	it .	ase d	etecto	or								•	le. 7] le. 8]	

Table2. Binary 14-bit Programmable Reference Counter Data Setting

Divide ratio (R)	R 14	R 13	R 12	R 11	R 10	R 9	R 8	R 7	R 6	R 5	R 4	R 3	R 2	R 1
5	0	0	0	0	0	0	0	0	0	0	0	1	0	1
6	0	0	0	0	0	0	0	0	0	0	0	1	1	0
•	•	•	•	•	•	•	•	•	•	•	•	•	•	
16383	1	1	1	1	1	1	1	1	1	1	1	1	1	1

Note: • Divide ratio less than 5 is prohibited.

Table.3 Test Purpose Bit Setting

Т 1	T 2	LD/fout pin state
L	L	Outputs frie.
Н	L	Outputs fr _{RF} .
L	Н	Outputs fpı⊧.
Н	Н	Outputs fprf.

Divide ratio (N)	N 11	N 10	N 9	N 8	N 7	N 6	N 5	N 4	N 3	N 2	N 1
5	0	0	0	0	0	0	0	0	1	0	1
6	0	0	0	0	0	0	0	0	1	1	0
	•	•	•	•	•	•	•	•	•	•	•
2047	1	1	1	1	1	1	1	1	1	1	1

Table.4 Binary 11-bit Programmable Counter Data Setting

Note: • Divide ratio less than 5 is prohibited.

Table.5 Binary 7-bit Swallow Counter Data Setting

Divide ratio (A)	A 7	A 6	A 5	A 4	A 3	A 2	A 1
0	0	0	0	0	0	0	0
1	0	0	0	0	0	0	1
			•	•	•	•	
127	1	1	1	1	1	1	1

Note: • Divide ratio (A) range = 0 to 127

Table. 6 Prescaler Data Setting

		SW = "H"	SW = "L"
Prescaler	IF-PLL	16/17	32/33
divide ratio	RF-PLL	64/65	128/129

Table. 7 Phase Comparator Phase Switching Data Setting

	FCIF/RF = H	FCIF/RF = L	
	DOIF/RF		
fr > fp	Н	L	
fr = fp	Z	Z	
fr < fp	L	Н	
VCO polarity	(1)	(2)	

Note: • Z = High-impedance

• Depending upon the VCO and LPF polarity, FC bit should be set.

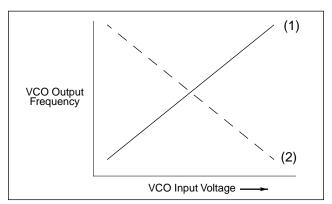
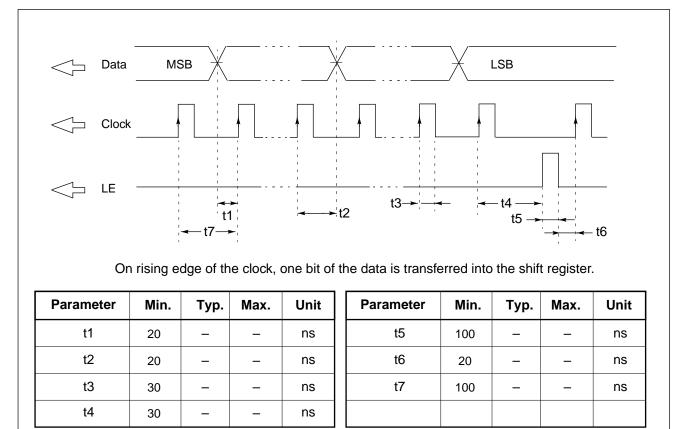


Table. 8 LD/fout Output Select Data Setting

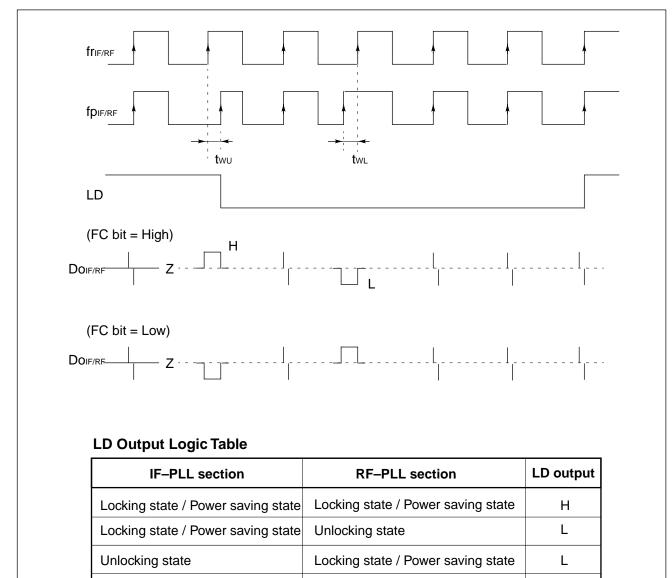
LDS	LD/fout output signal	
Н	fout (frif/RF, fpif/RF) signals	
L	LD signal	

Serial Data Input Timing



L

PHASE DETECTOR OUTPUT WAVEFORM



Note: • Phase error detection range = -2π to $+2\pi$

Unlocking state

- Pulses on DOIF/RF signals are output to prevent dead zone.
- LD output becomes low when phase error is two or more.
- LD output becomes high when phase error is twL or less and continues to be so for three cycles or more.

Unlocking state

twu and twL depend on OSCin input frequency as follows.
twu ≥ 8/fosc: i.e. twu ≥ 625ns when foscin = 12.8 MHz
twL ≤ 16/fosc: i.e. twL ≤ 1250ns when foscin = 12.8 MHz

■ POWER SAVING MODE (INTERMITTENT MODE CONTROL CIRCUIT)

Setting a $PS_{IF(RF)}$ pin to Low, IF-PLL (RF-PLL) enters into power saving mode resultant current consumption can be limited to $10\mu A$ (typ.). Setting PS pin to High, power saving mode is released so that the device works normally. In addition, the intermittent operation control circuit is included which helps smooth start up from stand by mode. In general, the power consumption can be saved by the intermittent operation that powering down or waking up the synthesizer. Such case, if the PLL is powered up uncontrolled, the resulting phase comparator output signal is unpredictable due to an undefined phase relation between reference frequency (fr) and comparison frequency (fp) and may in the worst case take longer time for lock up of the loop.

To prevent this, the intermittent operation control circuit enforces a limited error signal output of the phase detector during power up. Thus keeping the loop locked.

Allow 1 µs after frequency stabilization on power-up for exiting the power saving mode (PS: L to H) Serial data can be entered during the power saving mode.

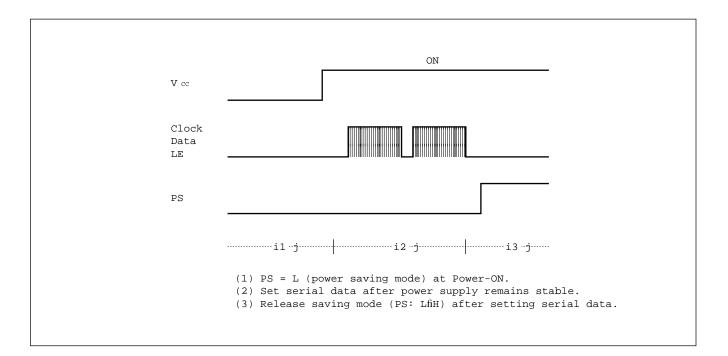
During the power saving mode, the corresponding section except for indispensable circuit for the power saving function stops working, then current consumption is reduced to $10\mu A$ per one PLL section.

At that time, the Do and LD become the same state as when a loop is locking. That is, the Do becomes high impedance.

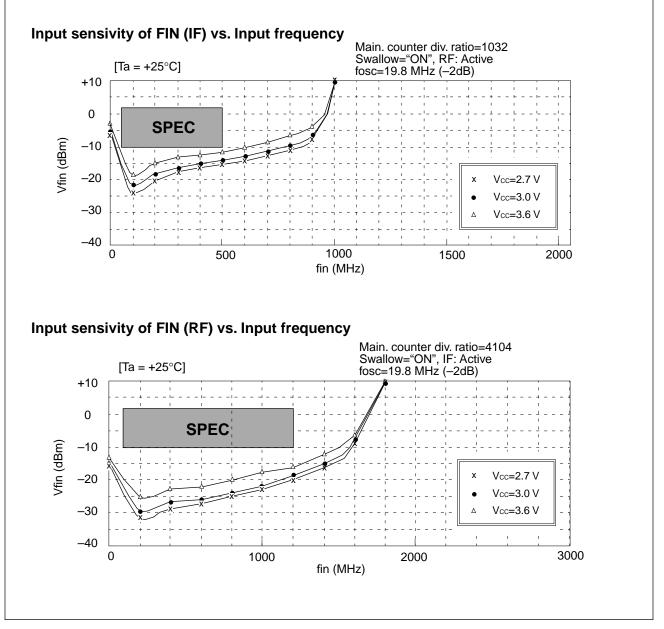
A VCO control voltage is naturally kept at the locking voltage which defined by a LPF's time constant. As a result of this, VCO's frequency is kept at the locking frequency.

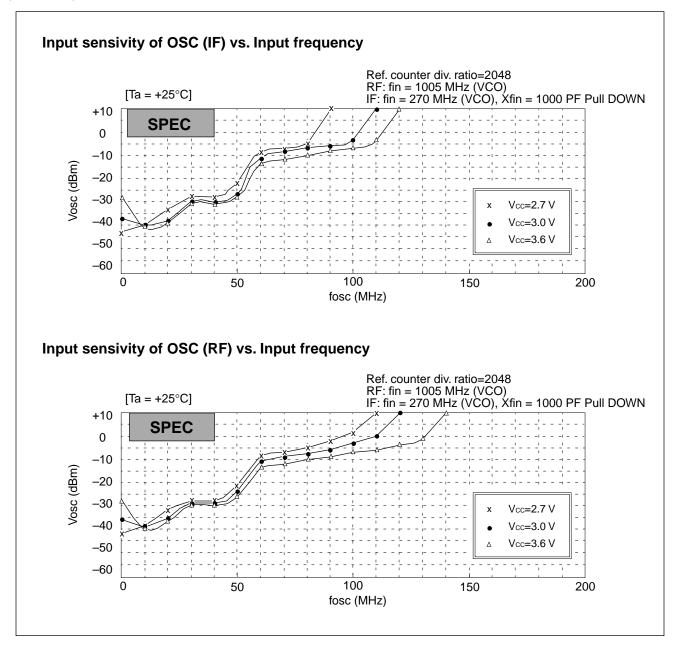
Note: PS pin must be set "L" at Power-ON. The power saving mode should be released at 1 μ s after the power supply becomes stable.

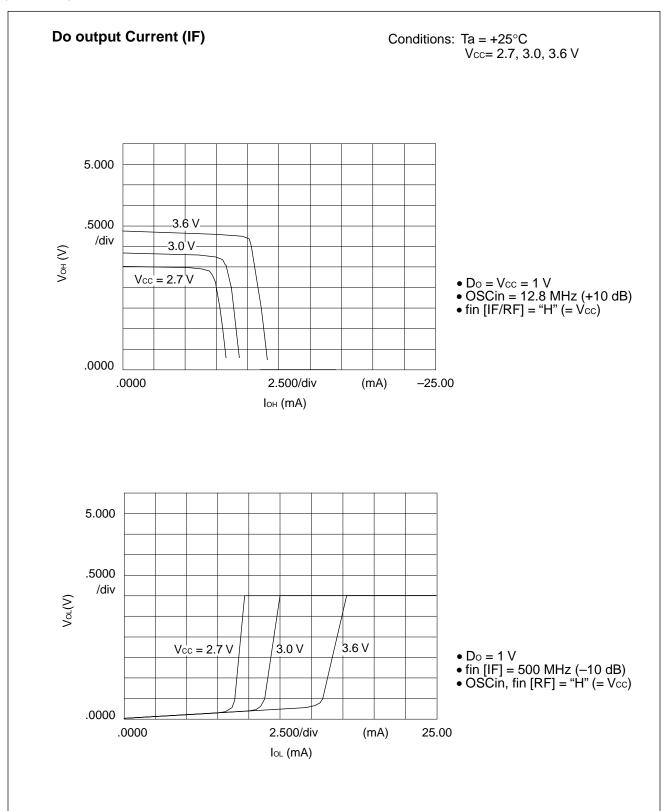
PSı⊧	PSRF	IF-PLL counters	RF-PLL counters	OSC input buffer
L	L	OFF	OFF	OFF
Н	L	ON	OFF	ON
L	Н	OFF	ON	ON
Н	Н	ON	ON	ON

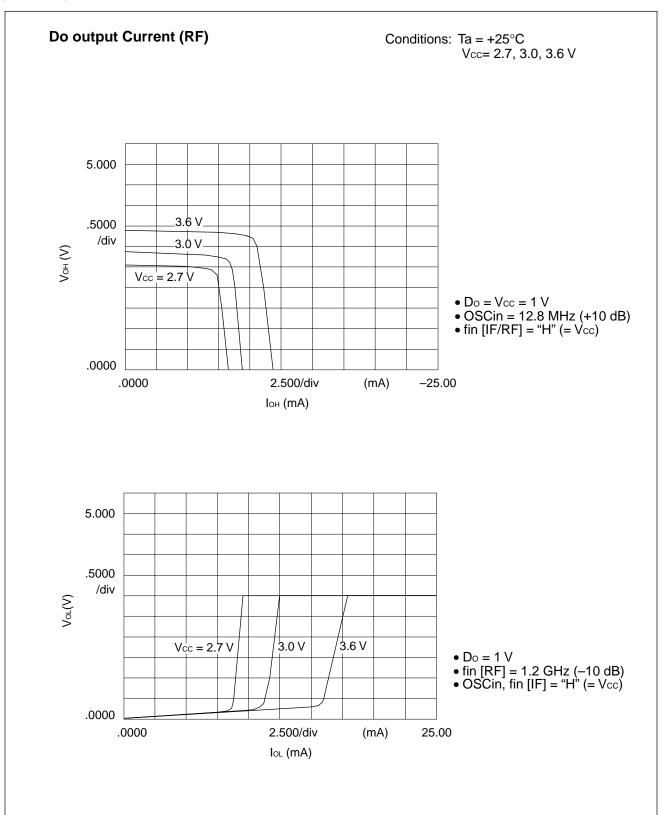


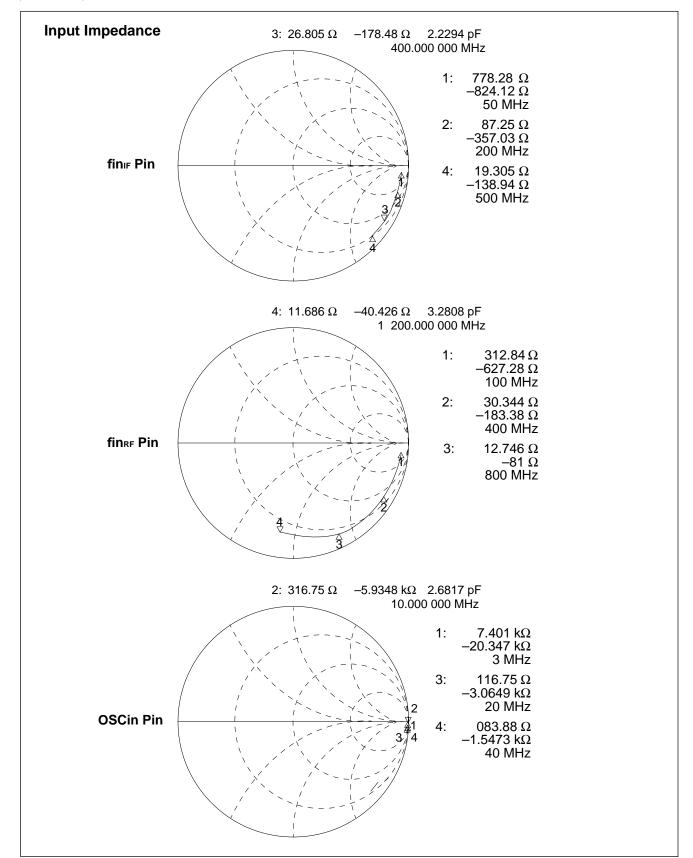
■ TYPICAL CHARACTERISTICS



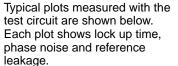


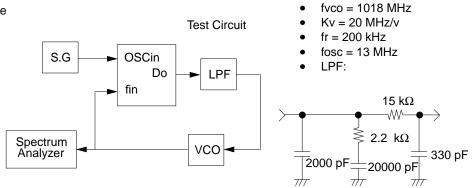


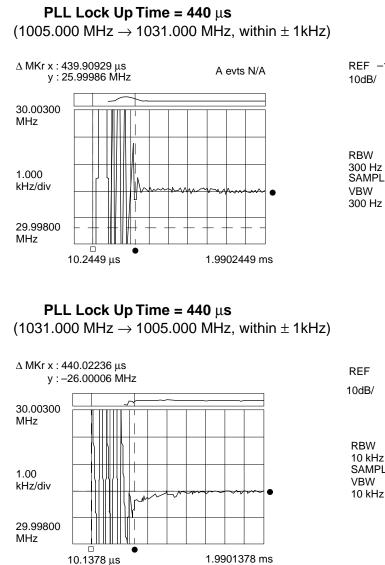




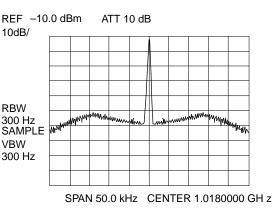
REFERENCE INFORMATION



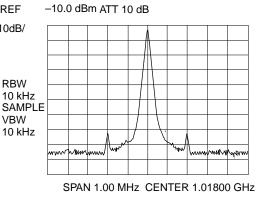


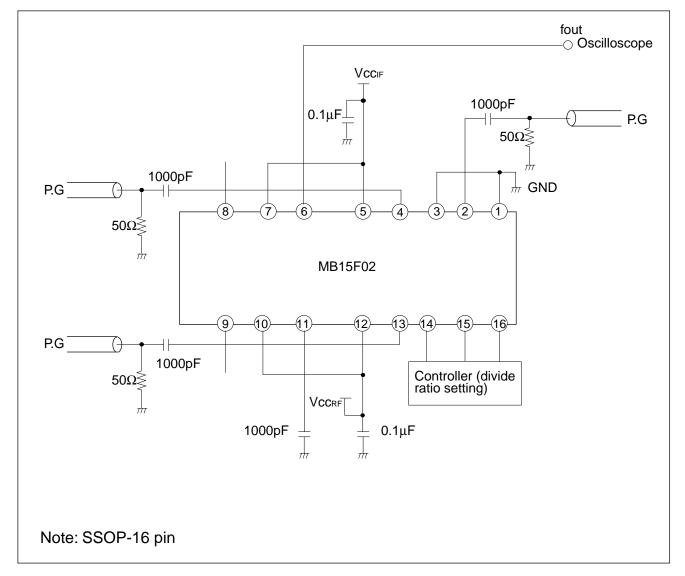


PLL Phase Noise @ within loop band = 75.5 dBc/Hz



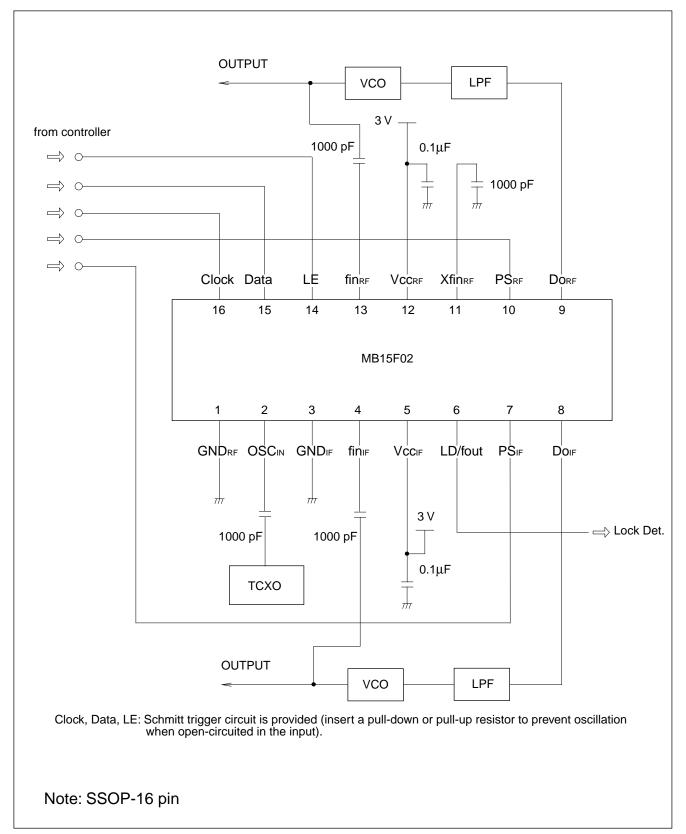
PLL Reference Leakage @ 200 kHz offset = 71.4 dBc





TEST CIRCUIT (PRESCALER INPUT/PROGRAMMABLE REFERENCE DIVIDER INPUT SENSITIVITY TEST)

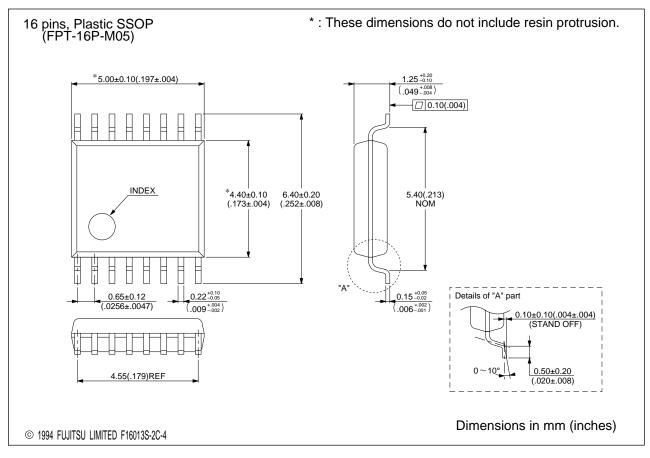
■ APPLICATION EXAMPLE

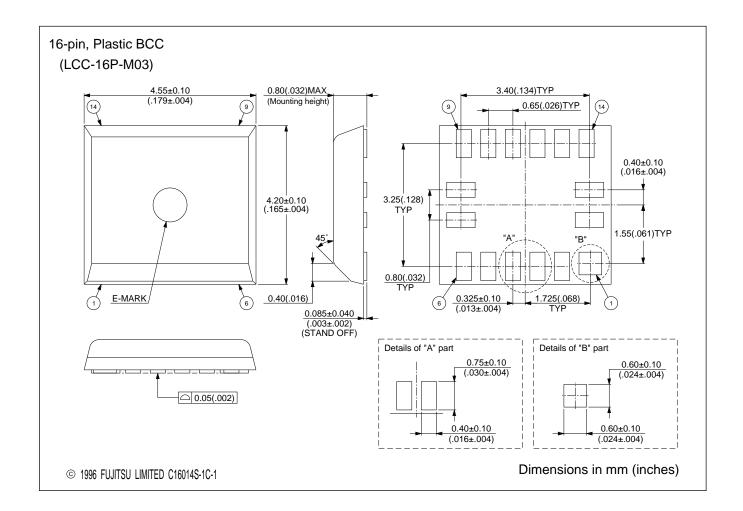


■ ORDERING INFORMATION

Part number	Package	Remarks
MB15F02 PFV	16 pin, Plastic SSOP (FPT-16P-M05)	
MB15F02 PV	16 pin, Plastic BCC (LCC-16P-M03)	

■ PACKAGE DIMENSIONS





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